

PR1001 - PR1007 FAST RECOVERY RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V CURRENT: 1.0 A

Features

- Diffused Junction
- Fast Switching for High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 30A Peak
- Low Reverse Leakage Current

Mechanical Data

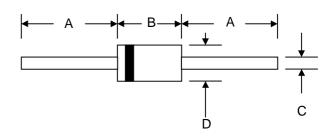
Case: DO-41Molded Plastic

 Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

Polarity: Cathode BandMarking: Type Number







| DO-41 | | | | | | | |
|----------------------|------|-------|--|--|--|--|--|
| Dim | Min | Max | | | | | |
| Α | 25.4 | _ | | | | | |
| В | 4.06 | 5.21 | | | | | |
| С | 0.71 | 0.864 | | | | | |
| D | 2.00 | 2.72 | | | | | |
| All Dimensions in mm | | | | | | | |

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

| Characteristic | | Symbol | PR1001 | PR1002 | PR1003 | PR1004 | PR1005 | PR1006 | PR1007 | Unit |
|---|---|--|-------------|--------|--------|--------|--------|--------|--------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 5) | | V _{RRM} V _{RWM} V _R | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| RMS Reverse Voltage | | V _{R(RMS)} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Average Rectified Output Current (Note 1) | @ T _A = 55°C | I _O | 1.0 | | | | | А | | |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load | | I _{FSM} | 30 | | | | | | Α | |
| Forward Voltage Drop | @ $I_F = 1.0A$ | V_{FM} | 1.3 | | | | | | V | |
| Peak Reverse Current at Rated DC Blocking Voltage (Note 5) | @ T _A = 25°C @ T _A = 100°C | I _{RM} | 5.0 50 | | | | | | μΑ | |
| Reverse Recovery Time (Note 3) | | t _{rr} | | 1 | 50 | | 250 | 50 | 00 | ns |
| Typical Total Capacitance (Note 2) | | Ст | 15 8 | | | | | | рF | |
| Typical Thermal Resistance Junction to Ambient | | R _{JA} | 95 | | | | | | °C/W | |
| Operating and Storage Temperature Range | | T _j , T _{STG} | -65 to +150 | | | | | | | °C |

Notes:

- 1. Valid provided that leads are maintained at ambient temperature at a distance of 9.5mm from the case.
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Measured with $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$. See figure 5.



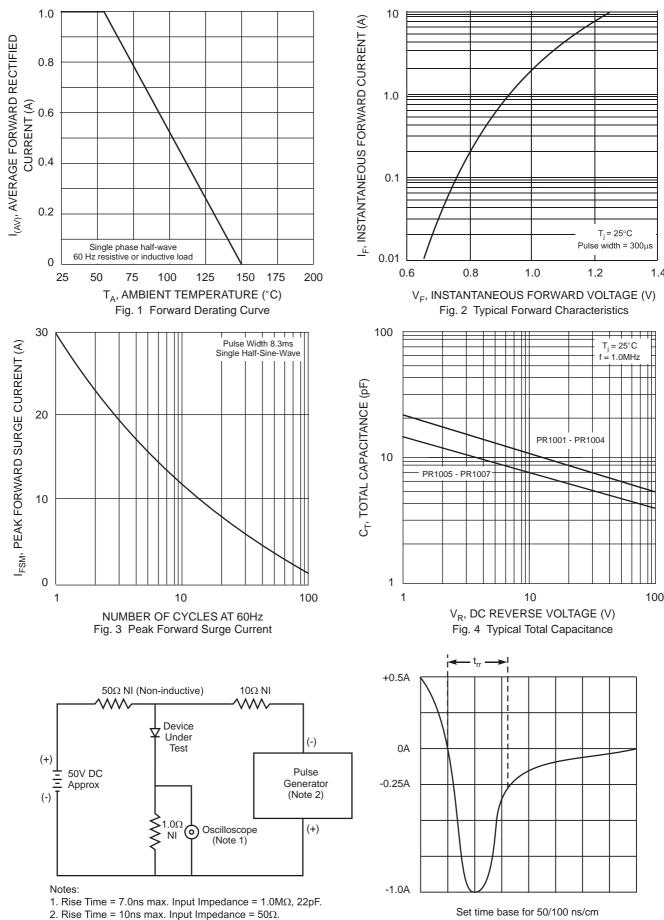


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit